FJX945

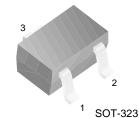
FAIRCHILD

SEMICONDUCTOR

FJX945

Audio Frequency Amplifier High Frequency OSC.

- Collector-Base Voltage V_{CBO}=60V
 High Current Gain Bandwidth Product f_T=300MHz (Typ)
- Complement to FJX733



1. Base 2. Emitter 3. Collector

NPN Epitaxial Silicon Transistor

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	60	V
V _{CEO}	Collector-Emitter Voltage	50	V
V _{EBO}	Emitter-Base Voltage	5	V
c	Collector Current	150	mA
P _C	Collector Power Dissipation	200	mW
Т _Ј	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

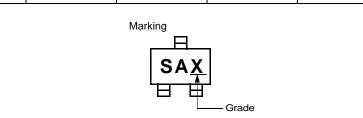
Absolute Maximum Ratings T_a=25°C unless otherwise noted

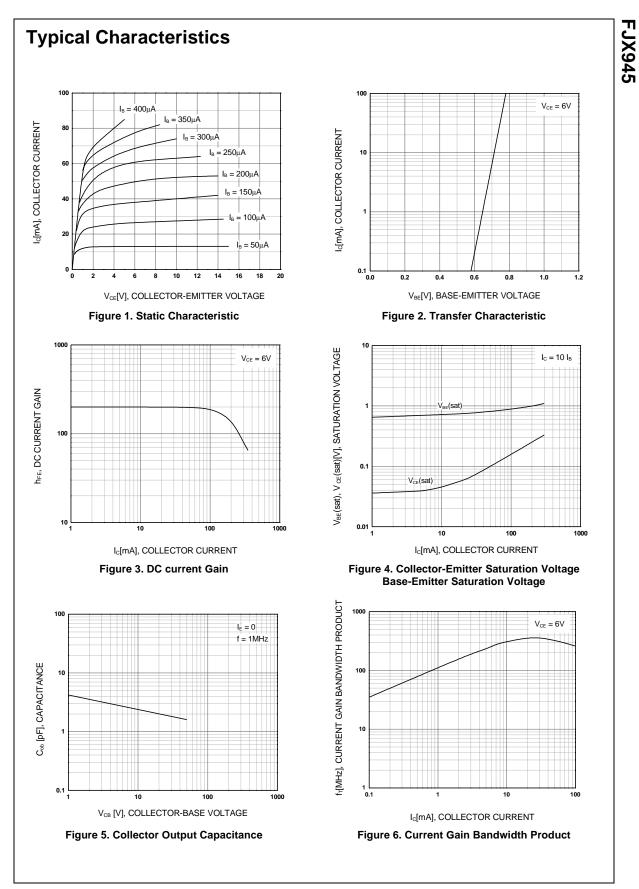
Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Parameter Test Condition Min.		Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =100μA, I _E =0	60			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =10mA, I _B =0	50			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E =10μΑ, I _C =0	5			V
I _{CBO}	Collector Cut-off Current	V _{CB} =40V, I _E =0			0.1	μΑ
I _{EBO}	Emitter Cut-off Current	V _{EB} =3V, I _C =0			0.1	μΑ
h _{FE}	DC Current Gain	V _{CE} =6V, I _C =1.0mA	40		700	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =100mA, I _B =10mA		0.15	0.3	V
f _T	Current Gain Bandwidth Product	V _{CE} =6V, I _C =10mA		300		MHz
C _{ob}	Output Capacitance	V _{CB} =6V, I _E =0 f=1MHz		2.5		pF
NF	Noise Figure	V _{CE} =6V, I _E = -0.5mA 4.0 f=1KHz, R _S =500Ω			dB	

h_{FE} Classification

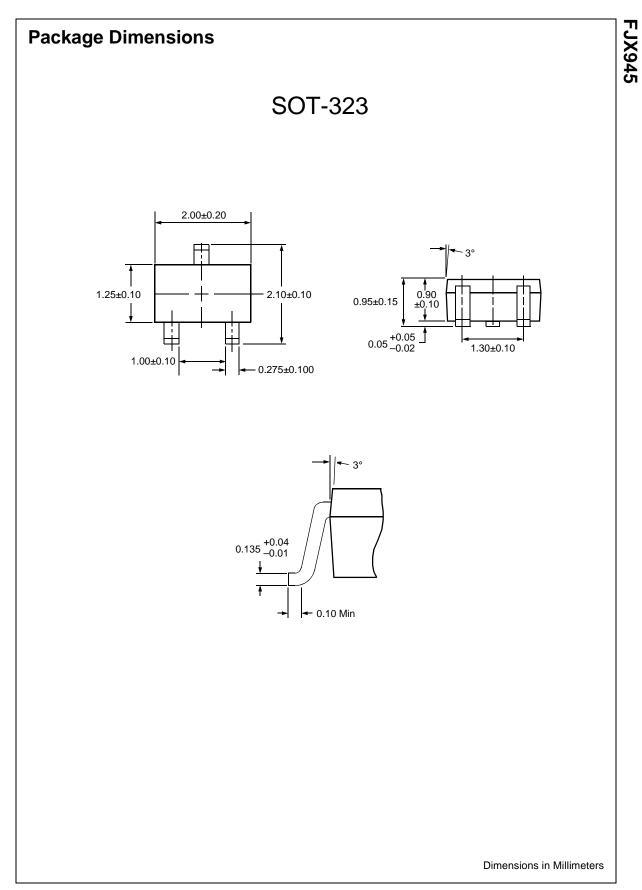
• =					
Classification	R	0	Y	G	L
h _{FE}	40 ~ 80	70 ~ 140	120 ~ 240	200 ~ 400	350 ~ 700





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Rev. A2, August 2002



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PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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